

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>	Docket Number (Optional) 50478-3700		IAP5 Rec'd PCT/PTO 30 AUG 2006 <small>Not yet assigned</small>	
	Applicant(s) Hideo Nagai et al.		10/591153	
	Filing Date 08/30/06 <i>Herewith</i>		Group Art Unit 2826 <i>Not yet assigned</i>	

U. S. PATENT DOCUMENTS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
/TT/		6,222,207	4.24.2001	Carter-Coman et al.			
/TT/		6,316,785	11.13.2001	Nunoue et al.			

U.S. PATENT APPLICATION PUBLICATIONS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
/TT/		2004-0031956	2.19.2004	Saxler			

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
/TT/		2003-110138	4.11.2003	Japan w/English Abstract			X	
/TT/		11-330552	11.30.1999	Japan w/English Abstract			X	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/TT/		Yamada, Motokazu et al; InGaN-Based Near-Ultraviolet and Blue-Light-Emitting Diodes with High External Quantum Efficiency Using a Patterned Sapphire Substrate and a Mesh Electrode; Jpn. J. Appl. Phys Vol. 41 (2002) pp. L1431-L1433, Part 2, No. 12B, December 15, 2002, The Japan Society of Applied Physics.
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EXAMINER	/Tan Tran/	DATE CONSIDERED	05/08/2008
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			